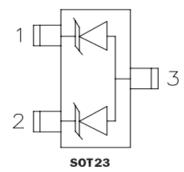


### Description

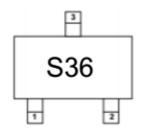
The JLE36ULT1-3 is a Uni-directional TVS diode array, \* utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting sensitive semiconductor components from damage. The JLE36ULT1-3 com plies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a lead-free SOT-23 package. It is designed to protect components which are connected to data and transmission lines from voltage surges.

### **Circuit Diagram**



Circuit and Pin Schematic

### **Marking Diagram**



**Transparent top view** S36:Device Marking Code

### Features

300W	peak	pulse	power (	8/20	us)	

- Low leakage: nA level
- Operating voltage: 36V
- Ultra low clamping voltage
- Two power line protects
  - Complies with following standards:
    - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 4A (8/20µs)
- RoHS Compliant
- \* Package: SOT-23

#### **Applications**

- \* Fast-charge battery chargers
- \* Power management system
- \* Cellular Handsets and Accessories
- Personal Digital Assistants
- \* Notebooks and Handhelds
- \* Portable Instrumentation
- \* Digital Cameras

### **Ordering Information**

P	art Number	Packaging	<b>Reel Size</b>
J	LE36ULT1-3	3000/Tape & Reel	7 inch



# Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

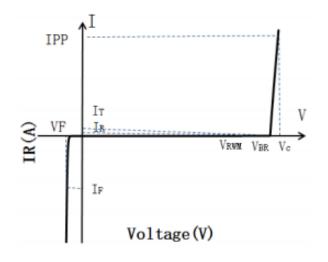
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	300	W
Peak Pulse Current (8/20µs)	IPP	4	А
ESD per IEC 61000-4-2 (Air)	VECD	±30	1-17
ESD per IEC 61000-4-2 (Contact)	VESD	±30	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Working Voltage	Vrwm				36	V
Breakdown Voltage	VBR	$I_T = 1mA$	38			V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 36V$			0.2	μΑ
Clamping Voltage	Vc	$I_{PP} = 1A (8 \times 20 \mu s \text{ pulse})$			50	V
Clamping Voltage	Vc	$I_{PP} = 4A (8 \times 20 \mu s \text{ pulse})$			75	V
Junction Capacitance	Cı	VR = 0V, $f = 1$ MHz,Pin 1 to Pin 3 or Pin 2 to Pin 3			40	pF

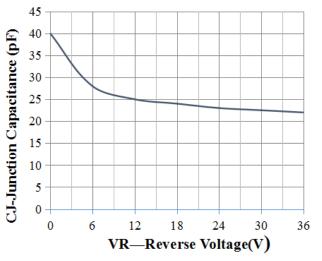
## **Portion Electronics Parameter**

Symbol	Parameter			
Ιτ	Test Current			
Ірр	Maximum Reverse Peak Pulse Current			
Vc	Clamping Voltage @Ic			



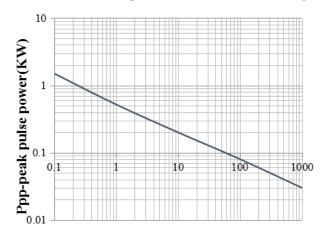
### JLE36ULT1-3



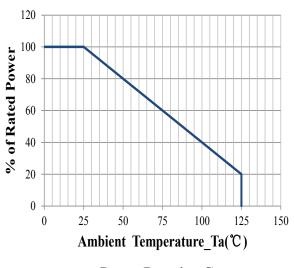


### Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise Specified)

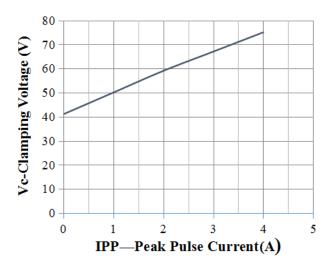
Junction Capacitance vs. Reverse Voltage



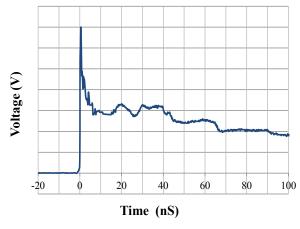
Peak Pulse Power vs. Pulse Time



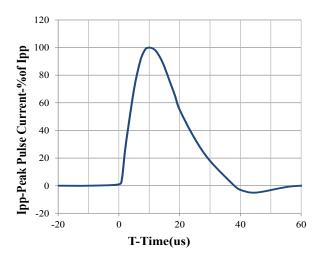
**Power Derating Curve** 



**Clamping Voltage vs. Peak Pulse Current** 



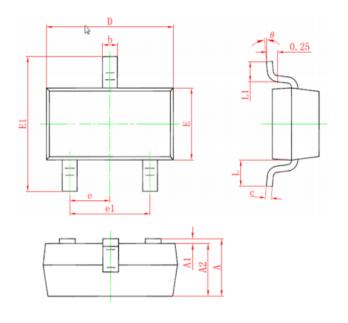
IEC61000-4-2 Pulse Waveform



8 X 20us Pulse Waveform

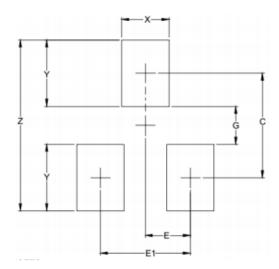


### SOT-23 Package Outline Drawing (Dimensions in millimeters)



		DIMENSIONS				
	MILLIMETERS			INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90		1.15	0.035		0.045
A1	0.00		0.10	0.000		0.004
A2	0.90		1.05	0.035		0.041
b	0.30		0.50	0.012		0.020
с	0.08		0.15	0.003		0.006
D	2.80		3.00	0.110		0.118
E	1.20		1.40	0.047		0.055
E1	2.25		2.25	0.089		0.100
е	0.95TYP			0.037TYP		
e1	1.80		2.00	0.071		0.079
L	0.55REF			0.022REF		
L1	0.30		0.50	0.012		0.020
Θ	0°		8°	0°		8°

### **Suggested Land Pattern**



CVM	DIMENSIONS				
SYM	INCHES	MILLIMETERS			
С	.087	2.20			
E	.037	0.95			
E1	.075	1.90			
G	.031	0.80			
х	.039	1.00			
Y	.055	1.40			
Z	.141	3.60			

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